Infineon Technologies - MB96F348ASBPQC-GSE2 Datasheet

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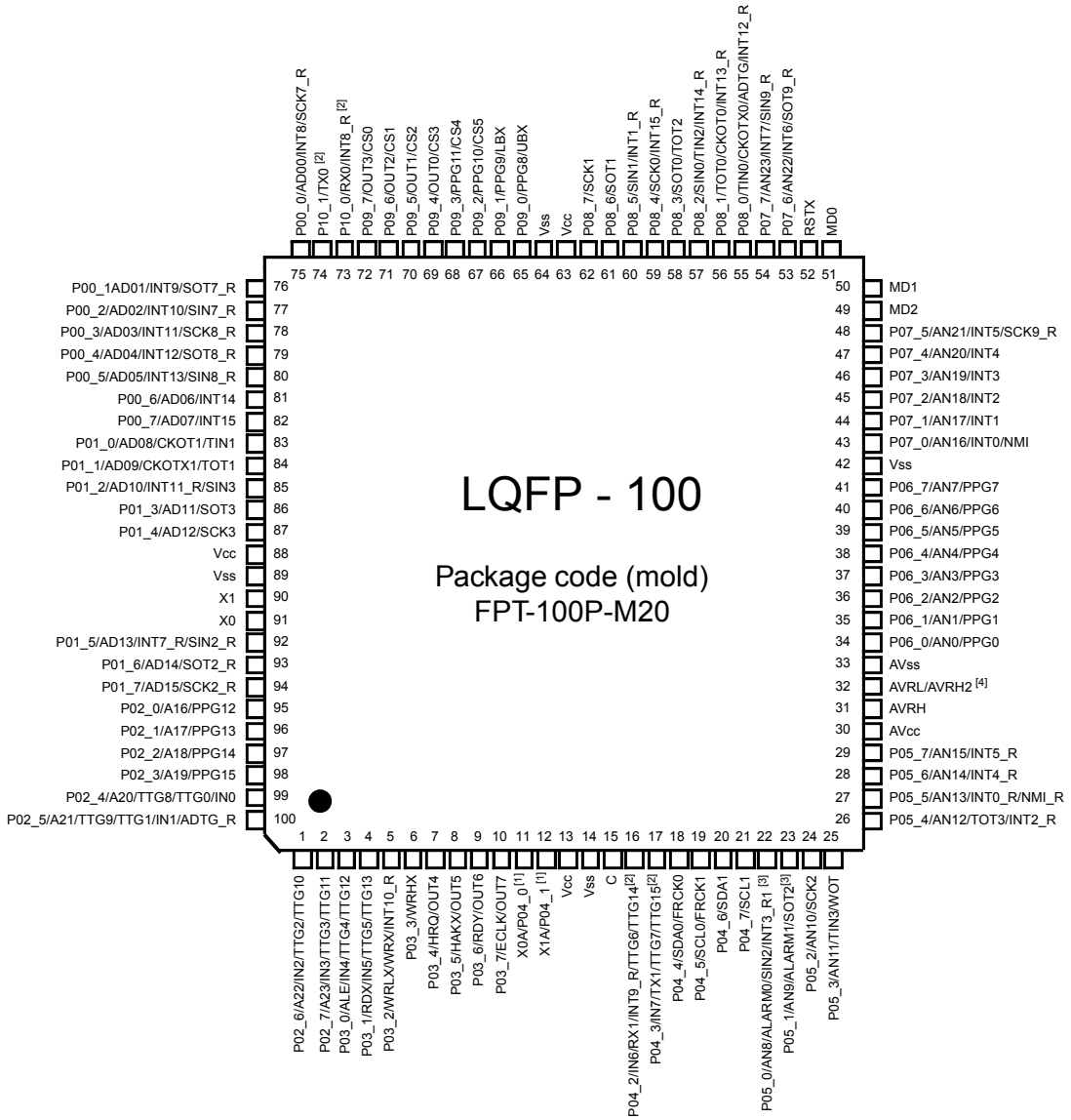
"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	F²MC-16FX
Core Size	16-Bit
Speed	56MHz
Connectivity	CANbus, EBI/EMI, I²C, LINbus, SCI, UART/USART
Peripherals	DMA, LVD, LVR, POR, PWM, WDT
Number of I/O	82
Program Memory Size	544KB (544K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	24K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 24x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-BQFP
Supplier Device Package	100-PQFP (14x20)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb96f348asbpqc-gse2

Feature	Description
Alarm comparator	■ Monitors an external voltage and generates an interrupt in case of a voltage lower or higher than the defined thresholds ■ Threshold voltages defined externally or generated internally ■ Status is readable, interrupts can be masked separately
I/O Ports	■ Virtually all external pins can be used as general purpose I/O ■ All push-pull outputs (except when used as I2C SDA/SCL line) ■ Bit-wise programmable as input/output or peripheral signal ■ Bit-wise programmable input enable ■ Bit-wise programmable input levels: Automotive / CMOS-Schmitt trigger / TTL (TTL levels not supported by all devices) ■ Bit-wise programmable pull-up resistor ■ Bit-wise programmable output driving strength for EMI optimization
Packages	■ 100-pin plastic QFP and LQFP
Flash Memory	■ Supports automatic programming, Embedded Algorithm ■ Write/Erase/Erase-Suspend/Resume commands ■ A flag indicating completion of the algorithm ■ Number of erase cycles: 10,000 times ■ Data retention time: 20 years ■ Erase can be performed on each sector individually ■ Sector protection ■ Flash Security feature to protect the content of the Flash ■ Low voltage detection during Flash erase

Figure 3. Pin assignment of MB96(F)34x (FPT-100P-M20)



[1]: MB96(F)34xyWy: X0A, X1A
MB96(F)34xySy: P04_0, P04_1

[2]: TX0, RX0, TX1, RX1 are not available on MB96(F)34xAyy or MB96(F)34xCyy
TX1, RX1 are not available on MB96F345Dyy or MB96F345Fyy

[3]: ALARM0, ALARM1 are not available on MB96F345Dyy or MB96F345Fyy

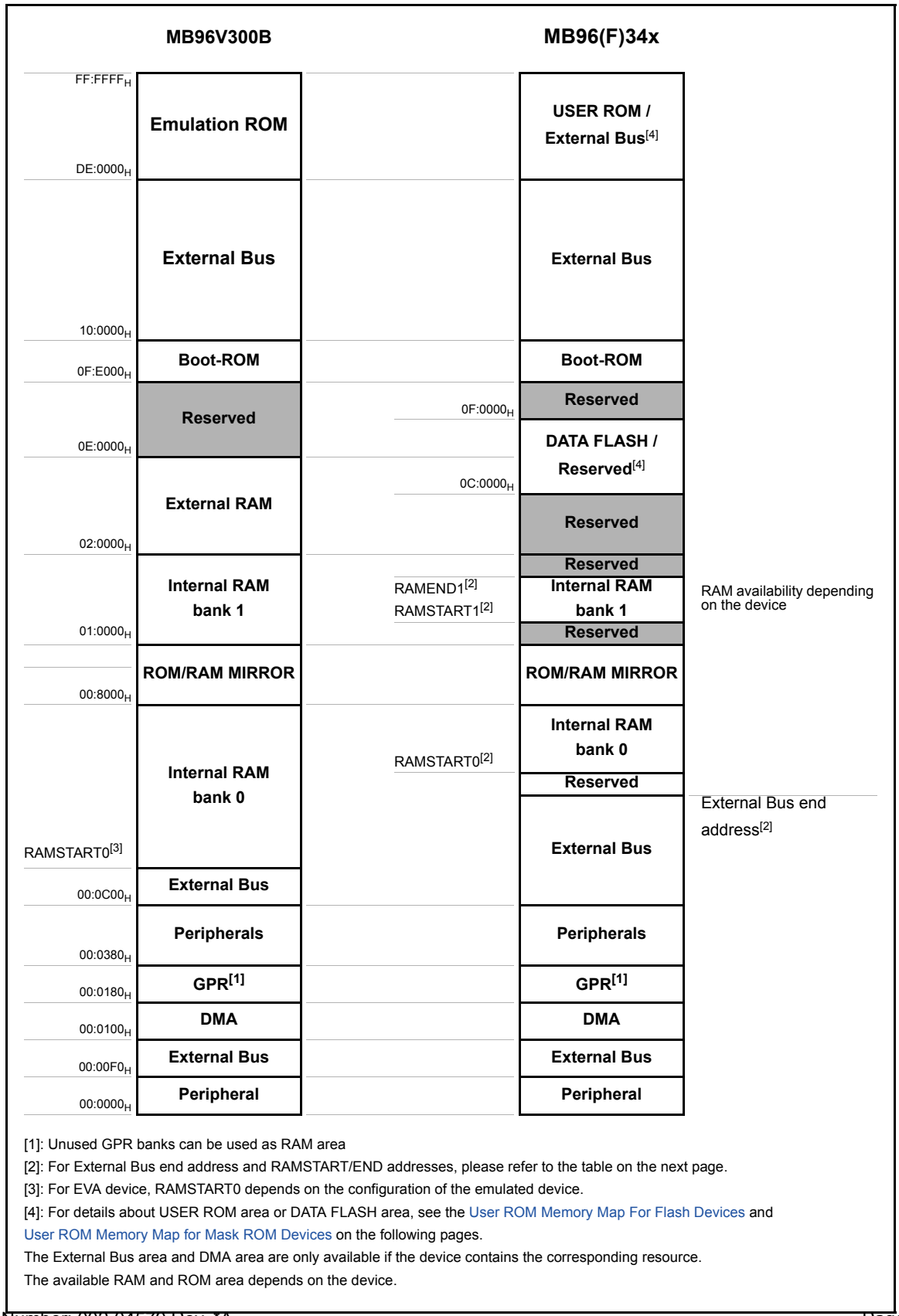
[4]: AVRH2 is not available on MB96F345Dyy or MB96F345Fyy

(FPT-100P-M20)

Remark:

MB96(F)34x products are pin-compatible to F^{2}MC-16LX family MB90340 series.

7. Memory Map



[1]: Unused GPR banks can be used as RAM area

[2]: For External Bus end address and RAMSTART/END addresses, please refer to the table on the next page.

[3]: For EVA device, RAMSTART0 depends on the configuration of the emulated device.

[4]: For details about USER ROM area or DATA FLASH area, see the User ROM Memory Map For Flash Devices and User ROM Memory Map for Mask ROM Devices on the following pages.

The External Bus area and DMA area are only available if the device contains the corresponding resource.

The available RAM and ROM area depends on the device.

■ RAM Start/End and External Bus End Addresses

Devices	Bank 0 RAM size	Bank 1 RAM size	External Bus end address	RAMSTART0	RAMSTART1	RAMEND1
MB96(F)345	8KByte	-	$00:21FF_H$	$00:6240_H$	-	-
MB96(F)346,MB96F347	16KByte	-	$00:21FF_H$	$00:4240_H$	-	-
MB96F348	24KByte	-	$00:21FF_H$	$00:2240_H$	-	-

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
000067_H	RLT1 - Reload Register - for reading			R
000068_H	RLT2 - Timer Control Status Register Low	TMCSRL2	TMCSR2	R/W
000069_H	RLT2 - Timer Control Status Register High	TMCSRH2		R/W
$00006A_H$	RLT2 - Reload Register - for writing		TMRLR2	W
$00006A_H$	RLT2 - Reload Register - for reading		TMR2	R
$00006B_H$	RLT2 - Reload Register - for writing			W
$00006B_H$	RLT2 - Reload Register - for reading			R
$00006C_H$	RLT3 - Timer Control Status Register Low	TMCSRL3	TMCSR3	R/W
$00006D_H$	RLT3 - Timer Control Status Register High	TMCSRH3		R/W
$00006E_H$	RLT3 - Reload Register - for writing		TMRLR3	W
$00006E_H$	RLT3 - Reload Register - for reading		TMR3	R
$00006F_H$	RLT3 - Reload Register - for writing			W
$00006F_H$	RLT3 - Reload Register - for reading			R
000070_H	RLT6 - Timer Control Status Register Low (dedic. RLT for PPG)	TMCSRL6	TMCSR6	R/W
000071_H	RLT6 - Timer Control Status Register High (dedic. RLT for PPG)	TMCSRH6		R/W
000072_H	RLT6 - Reload Register (dedic. RLT for PPG) - for writing		TMRLR6	W
000072_H	RLT6 - Reload Register (dedic. RLT for PPG) - for reading		TMR6	R
000073_H	RLT6 - Reload Register (dedic. RLT for PPG) - for writing			W
000073_H	RLT6 - Reload Register (dedic. RLT for PPG) - for reading			R
000074_H	PPG3-PPG0 - General Control register 1 Low	GCN1L0	GCN10	R/W
000075_H	PPG3-PPG0 - General Control register 1 High	GCN1H0		R/W
000076_H	PPG3-PPG0 - General Control register 2 Low	GCN2L0	GCN20	R/W
000077_H	PPG3-PPG0 - General Control register 2 High	GCN2H0		R/W
000078_H	PPG0 - Timer register		PTMR0	R
000079_H	PPG0 - Timer register			R
$00007A_H$	PPG0 - Period setting register		PCSR0	W
$00007B_H$	PPG0 - Period setting register			W
$00007C_H$	PPG0 - Duty cycle register		PDUT0	W
$00007D_H$	PPG0 - Duty cycle register			W
$00007E_H$	PPG0 - Control status register Low	PCNL0	PCN0	R/W
$00007F_H$	PPG0 - Control status register High	PCNH0		R/W
000080_H	PPG1 - Timer register		PTMR1	R

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
$0005AD_H$	PPG14 - Timer register			R
$0005AE_H$	PPG14 - Period setting register		PCSR14	W
$0005AF_H$	PPG14 - Period setting register			W
$0005B0_H$	PPG14 - Duty cycle register		PDUT14	W
$0005B1_H$	PPG14 - Duty cycle register			W
$0005B2_H$	PPG14 - Control status register Low	PCNL14	PCN14	R/W
$0005B3_H$	PPG14 - Control status register High	PCNH14		R/W
$0005B4_H$	PPG15 - Timer register		PTMR15	R
$0005B5_H$	PPG15 - Timer register			R
$0005B6_H$	PPG15 - Period setting register		PCSR15	W
$0005B7_H$	PPG15 - Period setting register			W
$0005B8_H$	PPG15 - Duty cycle register		PDUT15	W
$0005B9_H$	PPG15 - Duty cycle register			W
$0005BA_H$	PPG15 - Control status register Low	PCNL15	PCN15	R/W
$0005BB_H$	PPG15 - Control status register High	PCNH15		R/W
$0005BC_H$-$00065F_H$	Reserved			-
000660_H	Peripheral Resource Relocation Register 10	PRRR10		R/W
000661_H	Peripheral Resource Relocation Register 11	PRRR11		R/W
000662_H	Peripheral Resource Relocation Register 12	PRRR12		R/W
000663_H	Peripheral Resource Relocation Register 13	PRRR13		W
000664_H-$0006DF_H$	Reserved			-
$0006E0_H$	External Bus - Area configuration register 0 Low	EACL0	EAC0	R/W
$0006E1_H$	External Bus - Area configuration register 0 High	EACH0		R/W
$0006E2_H$	External Bus - Area configuration register 1 Low	EACL1	EAC1	R/W
$0006E3_H$	External Bus - Area configuration register 1 High	EACH1		R/W
$0006E4_H$	External Bus - Area configuration register 2 Low	EACL2	EAC2	R/W
$0006E5_H$	External Bus - Area configuration register 2 High	EACH2		R/W
$0006E6_H$	External Bus - Area configuration register 3 Low	EACL3	EAC3	R/W
$0006E7_H$	External Bus - Area configuration register 3 High	EACH3		R/W
$0006E8_H$	External Bus - Area configuration register 4 Low	EACL4	EAC4	R/W
$0006E9_H$	External Bus - Area configuration register 4 High	EACH4		R/W
$0006EA_H$	External Bus - Area configuration register 5 Low	EACL5	EAC5	R/W

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
$00074E_H$	CAN0 - IF2 Data A1 Low	IF2DTA1L0	IF2DTA10	R/W
$00074F_H$	CAN0 - IF2 Data A1 High	IF2DTA1H0		R/W
000750_H	CAN0 - IF2 Data A2 Low	IF2DTA2L0	IF2DTA20	R/W
000751_H	CAN0 - IF2 Data A2 High	IF2DTA2H0		R/W
000752_H	CAN0 - IF2 Data B1 Low	IF2DTB1L0	IF2DTB10	R/W
000753_H	CAN0 - IF2 Data B1 High	IF2DTB1H0		R/W
000754_H	CAN0 - IF2 Data B2 Low	IF2DTB2L0	IF2DTB20	R/W
000755_H	CAN0 - IF2 Data B2 High	IF2DTB2H0		R/W
000756_H-$00077F_H$	Reserved			-
000780_H	CAN0 - Transmission Request 1 Register Low	TREQR1L0	TREQR10	R
000781_H	CAN0 - Transmission Request 1 Register High	TREQR1H0		R
000782_H	CAN0 - Transmission Request 2 Register Low	TREQR2L0	TREQR20	R
000783_H	CAN0 - Transmission Request 2 Register High	TREQR2H0		R
000784_H-$00078F_H$	Reserved			-
000790_H	CAN0 - New Data 1 Register Low	NEWDT1L0	NEWDT10	R
000791_H	CAN0 - New Data 1 Register High	NEWDT1H0		R
000792_H	CAN0 - New Data 2 Register Low	NEWDT2L0	NEWDT20	R
000793_H	CAN0 - New Data 2 Register High	NEWDT2H0		R
000794_H-$00079F_H$	Reserved			-
$0007A0_H$	CAN0 - Interrupt Pending 1 Register Low	INTPND1L0	INTPND10	R
$0007A1_H$	CAN0 - Interrupt Pending 1 Register High	INTPND1H0		R
$0007A2_H$	CAN0 - Interrupt Pending 2 Register Low	INTPND2L0	INTPND20	R
$0007A3_H$	CAN0 - Interrupt Pending 2 Register High	INTPND2H0		R
$0007A4_H$-$0007AF_H$	Reserved			-
$0007B0_H$	CAN0 - Message Valid 1 Register Low	MSGVAL1L0	MSGVAL10	R
$0007B1_H$	CAN0 - Message Valid 1 Register High	MSGVAL1H0		R
$0007B2_H$	CAN0 - Message Valid 2 Register Low	MSGVAL2L0	MSGVAL20	R
$0007B3_H$	CAN0 - Message Valid 2 Register High	MSGVAL2H0		R
$0007B4_H$-$0007CD_H$	Reserved			-
$0007CE_H$	CAN0 - Output enable register	COER0		R/W
$0007CF_H$-$0007FF_H$	Reserved			-
000800_H	CAN1 - Control register Low	CTRLRL1	CTRLR1	R/W

Table 4: I/O map MB96(F)34x

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
000884_H-$00088F_H$	Reserved			-
000890_H	CAN1 - New Data 1 Register Low	NEWDT1L1	NEWDT11	R
000891_H	CAN1 - New Data 1 Register High	NEWDT1H1		R
000892_H	CAN1 - New Data 2 Register Low	NEWDT2L1	NEWDT21	R
000893_H	CAN1 - New Data 2 Register High	NEWDT2H1		R
000894_H-$00089F_H$	Reserved			-
$0008A0_H$	CAN1 - Interrupt Pending 1 Register Low	INTPND1L1	INTPND11	R
$0008A1_H$	CAN1 - Interrupt Pending 1 Register High	INTPND1H1		R
$0008A2_H$	CAN1 - Interrupt Pending 2 Register Low	INTPND2L1	INTPND21	R
$0008A3_H$	CAN1 - Interrupt Pending 2 Register High	INTPND2H1		R
$0008A4_H$-$0008AF_H$	Reserved			-
$0008B0_H$	CAN1 - Message Valid 1 Register Low	MSGVAL1L1	MSGVAL11	R
$0008B1_H$	CAN1 - Message Valid 1 Register High	MSGVAL1H1		R
$0008B2_H$	CAN1 - Message Valid 2 Register Low	MSGVAL2L1	MSGVAL21	R
$0008B3_H$	CAN1 - Message Valid 2 Register High	MSGVAL2H1		R
$0008B4_H$-$0008CD_H$	Reserved			-
$0008CE_H$	CAN1 - Output enable register	COER1		R/W
$0008CF_H$-$0009FF_H$	Reserved			-
$000A00_H$	DMA - IO address block register 0	IOABK0		R/W
$000A01_H$	DMA - IO address block register 1	IOABK1		R/W
$000A02_H$	DMA - IO address block register 2	IOABK2		R/W
$000A03_H$	DMA - IO address block register 3	IOABK3		R/W
$000A04_H$	DMA - IO address block register 4	IOABK4		R/W
$000A05_H$	DMA - IO address block register 5	IOABK5		R/W
$000A06_H$-$000BFF_H$	Reserved			-

Note: Any write access to reserved addresses in the I/O map should not be performed. A read access to a reserved address results in reading ‘X’.Registers of resources which are described in this table, but which are not supported by the device, should also be handled as “Reserved”.

14.3 DC characteristics

(T_A = -40°C to 125°C, V_{CC} = AV_{CC} = 3.0V to 5.5V, V_{SS} = AV_{SS} = 0V)

Parameter	Symbol	Pin	Condition	Value			Unit	Remarks
				Min	Typ	Max		
Input H voltage	V_{IH}	Port inputs Pnn_m	CMOS Hysteresis 0.8/0.2 input selected	0.8 V_{CC}	-	V_{CC} + 0.3	V	
			CMOS Hysteresis 0.7/0.3 input selected	0.7 V_{CC}	-	V_{CC} + 0.3	V	$V_{CC} \geq 4.5V$
				0.74 V_{CC}	-	V_{CC} + 0.3	V	$V_{CC} < 4.5V$
			AUTOMOTIVE Hysteresis input selected	0.8 V_{CC}	-	V_{CC} + 0.3	V	
			TTL input selected	2.0	-	V_{CC} + 0.3	V	
	V_{IHX0F}	X0	External clock in “Fast Clock Input mode”	0.8 V_{CC}	-	V_{CC} + 0.3	V	Not available in MB96F34xY/R/AxA
	V_{IHX0S}	X0,X1, X0A,X1A	External clock in “oscillation mode”	2.5	-	V_{CC} + 0.3	V	
	V_{IHR}	RSTX	-	0.8 V_{CC}	-	V_{CC} + 0.3	V	CMOS Hysteresis input
	V_{IHM}	MD2-MD0	-	V_{CC} - 0.3	-	V_{CC} + 0.3	V	
Input L voltage	V_{IL}	Port inputs Pnn_m	CMOS Hysteresis 0.8/0.2 input selected	V_{SS} - 0.3	-	0.2 V_{CC}	V	
			CMOS Hysteresis 0.7/0.3 input selected	V_{SS} - 0.3	-	0.3 V_{CC}	V	
			AUTOMOTIVE Hysteresis input selected	V_{SS} - 0.3	-	0.5 V_{CC}	V	$V_{CC} \geq 4.5V$
				V_{SS} - 0.3	-	0.46 V_{CC}		$V_{CC} < 4.5V$
			TTL input selected	V_{SS} - 0.3	-	0.8	V	
	V_{ILX0F}	X0	External clock in “Fast Clock Input mode”	V_{SS} - 0.3	-	0.2 V_{CC}	V	Not available in MB96F34xY/R/AxA
	V_{ILX0S}	X0,X1, X0A,X1A	External clock in “oscillation mode”	V_{SS} - 0.3	-	0.4	V	
	V_{ILR}	RSTX	-	V_{SS} - 0.3	-	0.2 V_{CC}	V	CMOS Hysteresis input
	V_{ILM}	MD2-MD0	-	V_{SS} - 0.3	-	V_{SS} + 0.3	V	
Output H voltage	V_{OH2}	Normal outputs	$4.5V \leq V_{CC} \leq 5.5V$, I_{OH} = -2mA / $3.0V \leq V_{CC} < 4.5V$, I_{OH} = -1.6mA	V_{CC} - 0.5	-	-	V	Driving strength set to 2mA
	V_{OH5}	Normal outputs	$4.5V \leq V_{CC} \leq 5.5V$, I_{OH} = -5mA / $3.0V \leq V_{CC} < 4.5V$, I_{OH} = -3mA	V_{CC} - 0.5	-	-	V	Driving strength set to 5mA
	V_{OH3}	3mA outputs	$4.5V \leq V_{CC} \leq 5.5V$, I_{OH} = -3mA / $3.0V \leq V_{CC} < 4.5V$, I_{OH} = -2mA	V_{CC} - 0.5	-	-	V	

(T_A = -40°C to 125°C, V_{CC} = AV_{CC} = 3.0V to 5.5V, V_{SS} = AV_{SS} = 0V)

Parameter	Symbol	Condition (at T_A)		Value			Remarks
				Typ	Max	Unit	
Power supply current in Run modes[1]	I_{CCRCH}	RC Run mode with CLKS1/2 = CLKB = CLKP1/2 = 2MHz (CLKMC, CLKPLL and CLKSC stopped)	+25°C	2.9	4	mA	Flash devices at 1 Flash wait state
			+125°C	3.5	6.5		
			+25°C	1.7	2.7	mA	MB96345/346 at 1 ROM wait state
			+125°C	2.3	4.7		
	I_{CCRCL}	RC Run mode with CLKS1/2 = CLKB = CLKP1/2 = 100kHz, SMCR:LPMS = 0 (CLKMC, CLKPLL and CLKSC stopped. Voltage regulator in high power mode)	+25°C	0.4	0.6	mA	MB96F346/F347/F348 at 1 Flash wait state
			+125°C	0.9	3.5		
			+25°C	0.18	0.3	mA	MB96F345 at 1 Flash wait state
			+125°C	0.68	3.3		
			+25°C	0.4	0.6	mA	MB96345/346 at 1 ROM wait state
			+125°C	0.9	2.4		
		RC Run mode with CLKS1/2 = CLKB = CLKP1/2 = 100kHz, SMCR:LPMS = 1 (CLKMC, CLKPLL and CLKSC stopped. Voltage regulator in low power mode, no Flash programming/erasing allowed)	+25°C	0.15	0.25	mA	Flash devices at 1 Flash wait state
			+125°C	0.65	3.2		
			+25°C	0.15	0.25	mA	MB96345/346 at 1 ROM wait state
			+125°C	0.65	2.1		
	I_{CCSUB}	Sub Run mode with CLKS1/2 = CLKB = CLKP1/2 = 32kHz (CLKMC, CLKPLL and CLKRC stopped, no Flash programming/erasing allowed)	+25°C	0.1	0.2	mA	Flash devices at 1 Flash wait state
			+125°C	0.6	3		
			+25°C	0.1	0.2	mA	MB96345/346 at 1 ROM wait state
			+125°C	0.6	2		

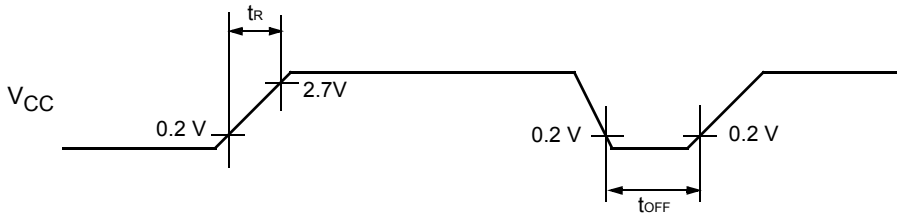
(T_A = -40°C to 125°C, V_{CC} = AV_{CC} = 3.0V to 5.5V, V_{SS} = AV_{SS} = 0V)

Parameter	Symbol	Condition (at T_A)		Value			Remarks
				Typ	Max	Unit	
Power supply current in Timer modes[1]	I_{CCTPLL}	PLL Timer mode with CLKMC = 4MHz, CLKPLL = 48MHz (CLKRC and CLKSC stopped. Core voltage at 1.9V)	+25°C	1.6	2	mA	Flash devices
			+125°C	2.1	5		
			+25°C	1.6	2	mA	MB96345/346
			+125°C	2.1	4		
	$I_{CCTMAIN}$	Main Timer mode with CLKMC = 4MHz, SMCR:LPMSS = 0 (CLKPLL, CLKRC and CLKSC stopped. Voltage regulator in high power mode)	+25°C	0.35	0.5	mA	MB96F346/F347/F348
			+125°C	0.85	3.3		
			+25°C	0.13	0.2	mA	MB96F345
			+125°C	0.63	3		
			+25°C	0.35	0.5	mA	MB96345/346
			+125°C	0.85	2.3		
		Main Timer mode with CLKMC = 4MHz, SMCR:LPMSS = 1 (CLKPLL, CLKRC and CLKSC stopped. Voltage regulator in low power mode)	+25°C	0.1	0.15	mA	Flash devices
			+125°C	0.6	2.9		
			+25°C	0.1	0.15		MB96345/346
			+125°C	0.6	1.9		
	I_{CCTRCH}	RC Timer mode with CLKRC = 2MHz, SMCR:LPMSS = 0 (CLKMC, CLKPLL and CLKSC stopped. Voltage regulator in high power mode)	+25°C	0.35	0.5	mA	MB96F346/F347/F348
			+125°C	0.85	3.3		
			+25°C	0.13	0.2	mA	MB96F345
			+125°C	0.63	3		
			+25°C	0.35	0.5	mA	MB96345/346
			+125°C	0.85	2.3		
		RC Timer mode with CLKRC = 2MHz, SMCR:LPMSS = 1 (CLKMC, CLKPLL and CLKSC stopped. Voltage regulator in low power mode)	+25°C	0.1	0.15	mA	Flash devices
			+125°C	0.6	2.9		
			+25°C	0.1	0.15	mA	MB96345/346
			+125°C	0.6	1.9		

14.4.4 Power On Reset timing

(T_A = -40°C to 125°C, V_{CC} = AV_{CC} = 3.0V to 5.5V, V_{SS} = AV_{SS} = 0V)

Parameter	Symbol	Pin	Value			Unit	Remarks
			Min	Typ	Max		
Power on rise time	t_R	Vcc	0.05	-	30	ms	
Power off time	t_{OFF}	Vcc	1	-	-	ms	



If the power supply is changed too rapidly, a power-on reset may occur.
We recommend a smooth startup by restraining voltages when changing the power supply voltage during operation, as shown in the figure below.

(T_A = –40°C to +125°C, V_{CC} = 5.0 V ± 10%, V_{SS} = 0.0 V, IO_{drive} = 5mA, C_L = 50pF)

Parameter	Symbol	Pin	Conditions	Value		Unit	Remarks
				Min	Max		
RDX ↑ ⇒ ALE ↑ time	t_{RHLH}	RDX, ALE	EACL:STS=1 and EACL:ACE=1	$3t_{CYC}/2 - 10$	-	ns	
			other ECL:STS, EACL:ACE setting	$t_{CYC}/2 - 10$	-		
Valid address ⇒ ECLK ↑ time	t_{AVCH}	A[23:16], ECLK	-	$t_{CYC} - 15$	-	ns	
	t_{ADVCH}	AD[15:0], ECLK		$t_{CYC}/2 - 15$	-		
RDX ↓ ⇒ ECLK ↑ time	t_{RLCH}	RDX, ECLK	-	$t_{CYC}/2 - 10$	-	ns	
ALE ↓ ⇒ RDX ↓ time	t_{LLRL}	ALE, RDX	EACL:STS=0	$t_{CYC}/2 - 10$	-	ns	
			EACL:STS=1	– 10	-		
ECLK↑ ⇒ Valid data input	t_{CHDV}	AD[15:0], ECLK	-	-	$t_{CYC} - 50$	ns	

(T_A = –40°C to +125°C, V_{CC} = 3.0 to 4.5V, V_{SS} = 0.0 V, IO_{drive} = 5mA, C_L = 50pF)

Parameter	Symbol	Pin	Conditions	Value		Unit	Remarks
				Min	Max		
ALE pulse width	t_{LHLL}	ALE	EACL:STS=0 and EACL:ACE=0	$t_{CYC}/2 - 8$	-	ns	
			EACL:STS=1	$t_{CYC} - 8$	-		
			EACL:STS=0 and EACL:ACE=1	$3t_{CYC}/2 - 8$	-		
Valid address ⇒ ALE ↓ time	t_{AVLL}	ALE, A[23:16],	EACL:STS=0 and EACL:ACE=0	$t_{CYC} - 20$	-	ns	
			EACL:STS=1 and EACL:ACE=0	$3t_{CYC}/2 - 20$	-		
			EACL:STS=0 and EACL:ACE=1	$2t_{CYC} - 20$	-		
			EACL:STS=1 and EACL:ACE=1	$5t_{CYC}/2 - 20$	-		
	t_{ADVLL}	ALE, AD[15:0]	EACL:STS=0 and EACL:ACE=0	$t_{CYC}/2 - 20$	-	ns	
			EACL:STS=1 and EACL:ACE=0	$t_{CYC} - 20$	-		
			EACL:STS=0 and EACL:ACE=1	$3t_{CYC}/2 - 20$	-		
			EACL:STS=1 and EACL:ACE=1	$2t_{CYC} - 20$	-		
ALE ↓ ⇒ Address valid time	t_{LLAX}	ALE, AD[15:0]	EACL:STS=0	$t_{CYC}/2 - 20$	-	ns	
			EACL:STS=1	-20	-		
Valid address ⇒ RDX ↓ time	t_{AVRL}	RDX, A[23:16]	EACL:ACE=0	$3t_{CYC}/2 - 20$	-	ns	
			EACL:ACE=1	$5t_{CYC}/2 - 20$	-		
	t_{ADVRL}	RDX, AD[15:0]	EACL:ACE=0	$t_{CYC} - 20$	-	ns	
			EACL:ACE=1	$2t_{CYC} - 20$	-		

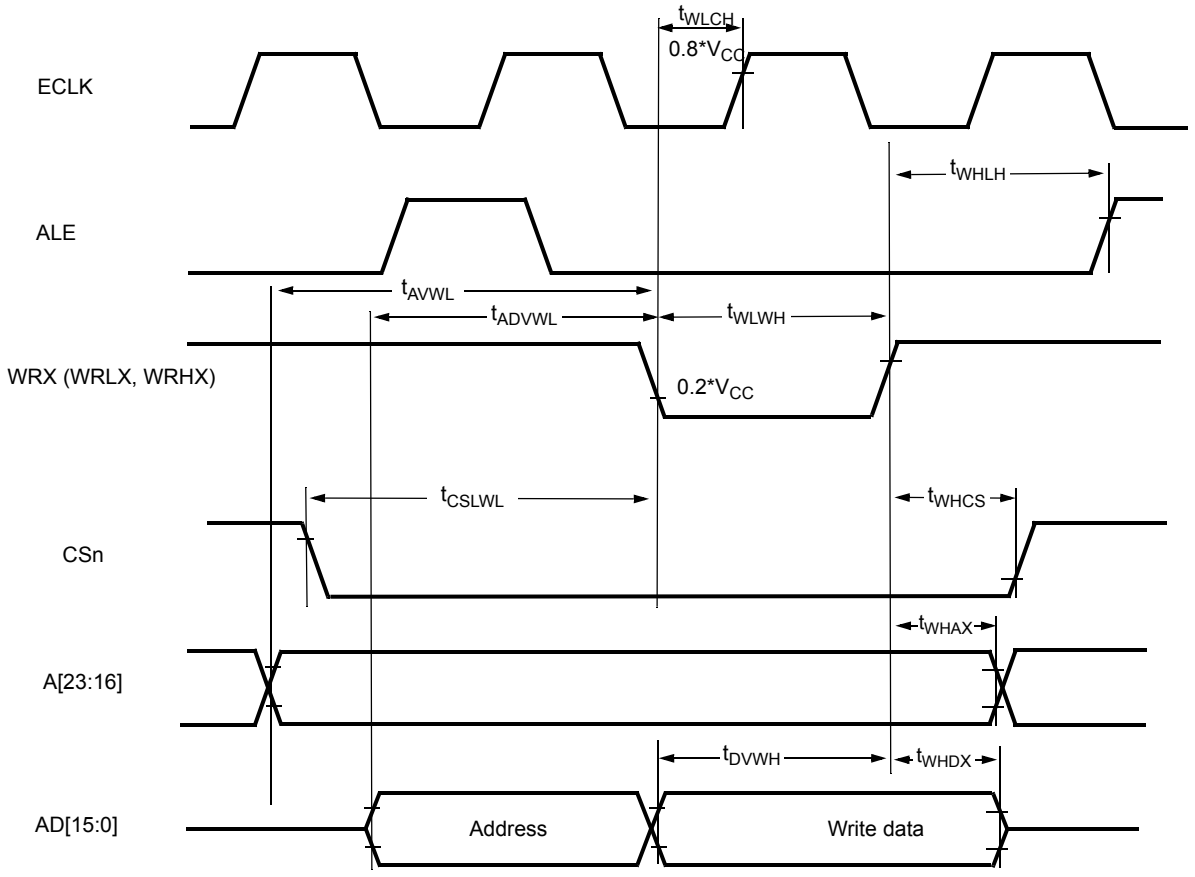
14.4.9 Bus Timing (Write)

(T_A = –40°C to +125°C, V_{CC} = 5.0 V ± 10%, V_{SS} = 0.0 V, IO_{drive} = 5mA, C_L = 50pF)

Parameter	Symbol	Pin	Condition	Value		Unit	Remarks
				Min	Max		
Valid address ⇒ WRX ↓ time	t_{AVWL}	WRX, WRLX, WRHX, A[23:16]	EACL:ACE=0	$3t_{CYC}/2 - 15$	-	ns	
			EACL:ACE=1	$5t_{CYC}/2 - 15$	-		
	t_{ADVWL}	WRX, WRLX, WRHX, AD[15:0]	EACL:ACE=0	$t_{CYC} - 15$	-	ns	
			EACL:ACE=1	$2t_{CYC} - 15$	-		
WRX pulse width	t_{WLWH}	WRX, WRXL, WRHX	-	$t_{CYC} - 5$	-	ns	w/o cycle extension
Valid data output ⇒ WRX ↑ time	t_{DVWH}	WRX, WRLX, WRHX, AD[15:0]	-	$t_{CYC} - 20$	-	ns	w/o cycle extension
WRX ↑ ⇒ Data hold time	t_{WHDX}	WRX, WRLX, WRHX, AD[15:0]	-	$t_{CYC}/2 - 15$	-	ns	
WRX ↑ ⇒ Address valid time	t_{WHAX}	WRX, WRLX, WRHX, A[23:16]	-	$t_{CYC}/2 - 15$	-	ns	
WRX ↑ ⇒ ALE ↑ time	t_{WHLH}	WRX, WRLX, WRHX, ALE	EBM:ACE=1 and EACL:STS=1	$2t_{CYC} - 10$	-	ns	
			other EBM:ACE and EACL:STS setting	$t_{CYC} - 10$	-		
WRX ↓ ⇒ ECLK ↑ time	t_{WLCH}	WRX, WRLX, WRHX, ECLK	-	$t_{CYC}/2 - 10$	-	ns	
CSn ⇒ WRX time	t_{CSLWL}	WRX, WRLX, WRHX, CSn	EACL:ACE=0	-	$3t_{CYC}/2 - 15$	ns	
			EACL:ACE=1	-	$5t_{CYC}/2 - 15$		
WRX ⇒ CSn time	t_{WHCSH}	WRX, WRLX, WRHX, CSn	-	$t_{CYC}/2 - 15$	-	ns	

(T_A = –40°C to +125°C, V_{CC} = 3.0 to 4.5V, V_{SS} = 0.0 V, IO_{drive} = 5mA, C_L = 50pF)

Parameter	Symbol	Pin	Condition	Value		Unit	Remarks
				Min	Max		
Valid address ⇒ WRX ↓ time	t_{AVWL}	WRX, WRLX, WRHX, A[23:16]	EACL:ACE=0	$3t_{CYC}/2 - 20$	-	ns	
			EACL:ACE=1	$5t_{CYC}/2 - 20$	-		
	t_{ADVWL}	WRX, WRLX, WRHX, AD[15:0]	EACL:ACE=0	$t_{CYC} - 20$	-	ns	
			EACL:ACE=1	$2t_{CYC} - 20$	-		



Refer to the Hardware Manual for detailed Timing Charts

14.4.10 Ready Input Timing

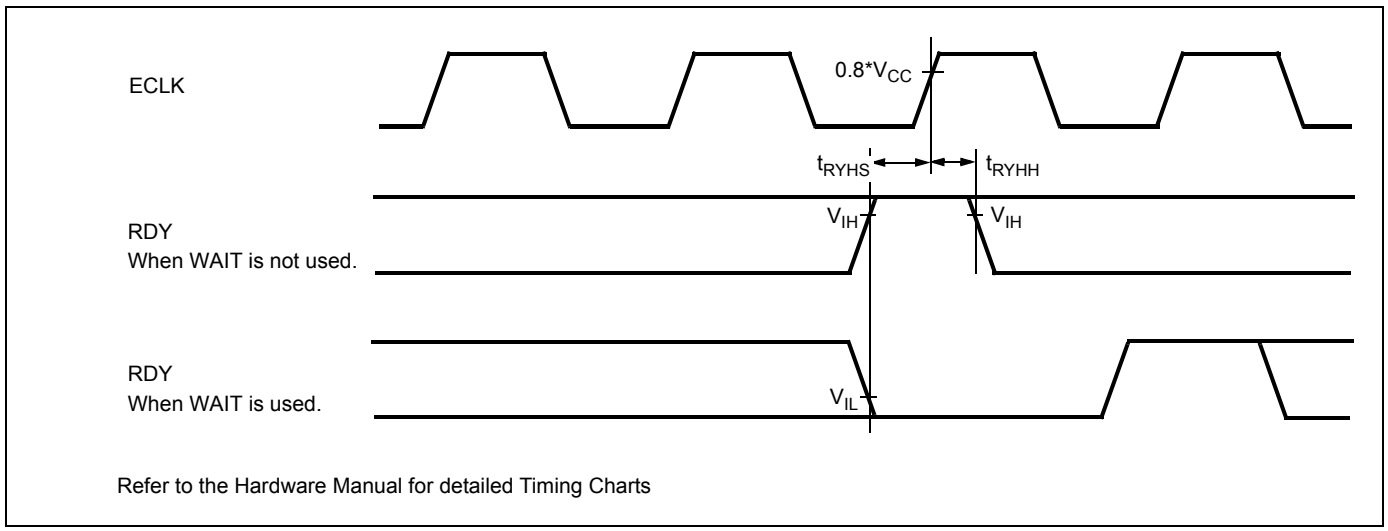
(T_A = –40°C to +125°C, V_{CC} = 5.0 V ± 10%, V_{SS} = 0.0 V, IO_{drive} = 5mA, C_L = 50pF)

Parameter	Symbol	Pin	Test Condition	Rated Value		Units	Remarks
				Min	Max		
RDY setup time	t_{RYHS}	RDY	-	35	-	ns	
RDY hold time	t_{RYHH}	RDY		0	-	ns	

(T_A = –40°C to +125°C, V_{CC} = 3.0 to 4.5V, V_{SS} = 0.0 V, IO_{drive} = 5mA, C_L = 50pF)

Parameter	Symbol	Pin	Test Condition	Rated Value		Units	Remarks
				Min	Max		
RDY setup time	t_{RYHS}	RDY	-	45	-	ns	
RDY hold time	t_{RYHH}	RDY		0	-	ns	

Note: If the RDY setup time is insufficient, use the auto-ready function.



Refer to the Hardware Manual for detailed Timing Charts

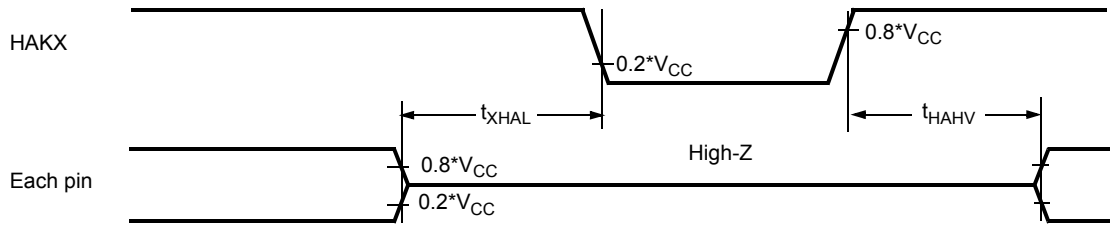
14.4.11 Hold Timing

(T_A = –40°C to +125°C, V_{CC} = 5.0 V ± 10%, V_{SS} = 0.0 V, IO_{drive} = 5mA, C_L = 50pF)

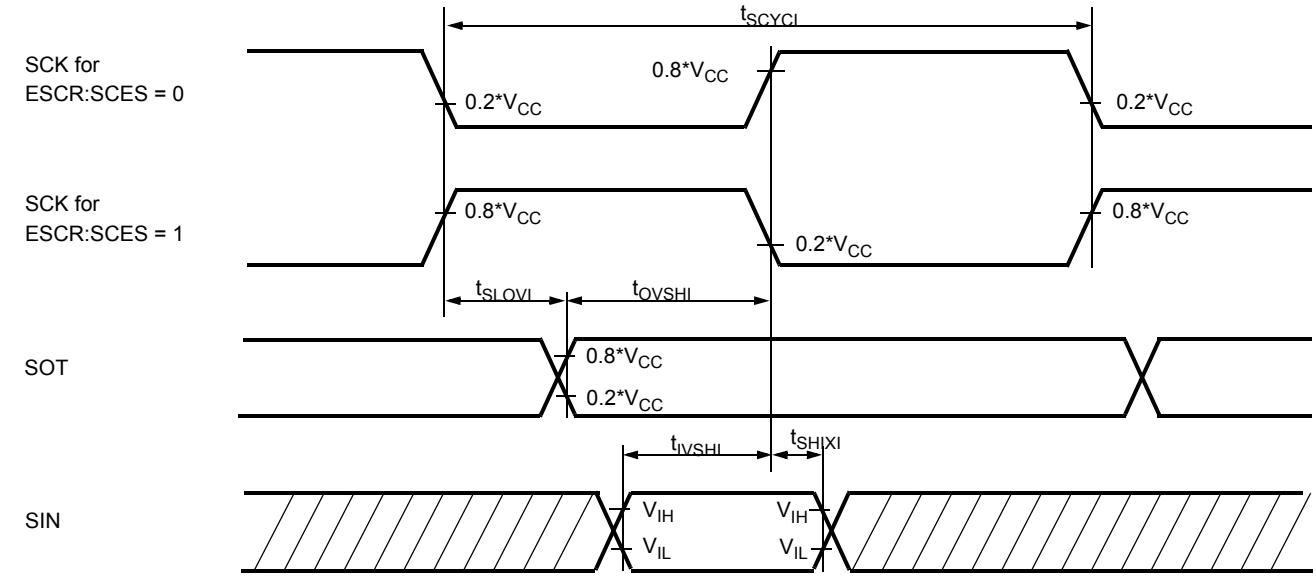
Parameter	Symbol	Pin	Condition	Value		Units	Remarks
				Min	Max		
Pin floating ⇒ HAKX ↓ time	t_{XHAL}	HAKX	-	t_{CYC} – 20	t_{CYC} + 20	ns	
HAKX ↑ time ⇒ Pin valid time	t_{HAHV}	HAKX		t_{CYC} – 20	t_{CYC} + 20	ns	

(T_A = –40°C to +125°C, V_{CC} = 3.0 to 4.5V, V_{SS} = 0.0 V, IO_{drive} = 5mA, C_L = 50pF)

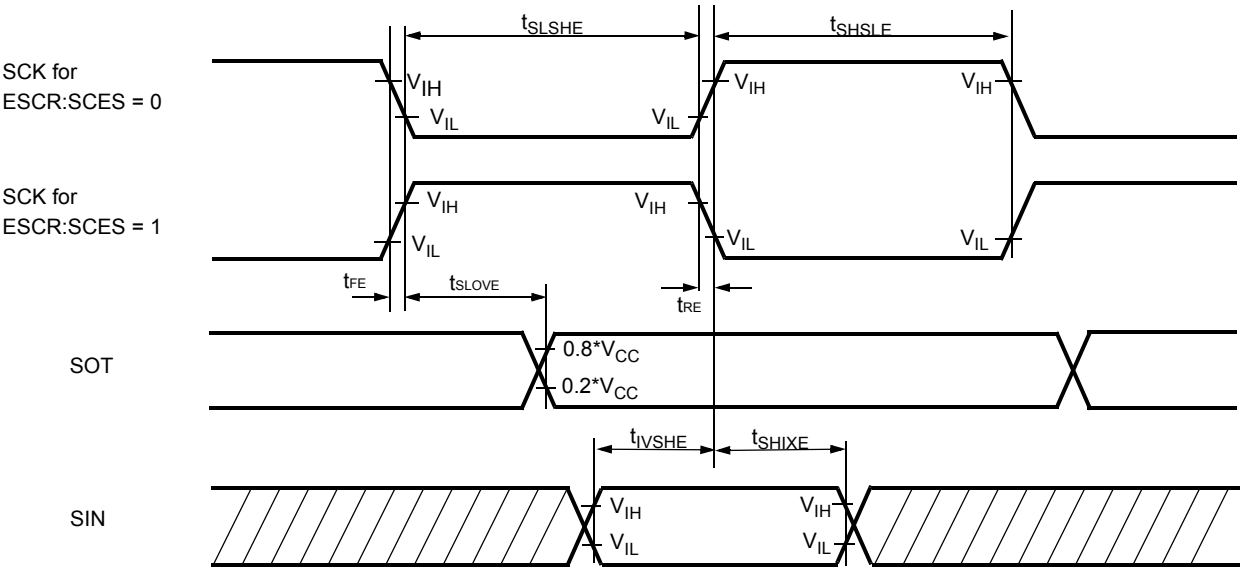
Parameter	Symbol	Pin	Condition	Value		Units	Remarks
				Min	Max		
Pin floating ⇒ HAKX ↓ time	t_{XHAL}	HAKX	-	t_{CYC} – 25	t_{CYC} + 25	ns	
HAKX ↑ time ⇒ Pin valid time	t_{HAHV}	HAKX		t_{CYC} – 25	t_{CYC} + 25	ns	



Refer to the Hardware Manual for detailed Timing Charts



Internal Shift Clock Mode



External Shift Clock Mode

14.6 Alarm Comparator

(T_A = -40 °C to +125 °C, V_{CC} = AV_{CC} = 3.0V - 5.5V, V_{SS} = AV_{SS} = 0V)

Parameter	Symbol	Pin	Value			Unit	Remarks
			Min	Typ	Max		
Power supply current	I_{A5ALMF}	AV_{CC}	-	25	45	µA	Alarm comparator enabled in fast mode (one channel)
	I_{A5ALMS}		-	7	13	µA	Alarm comparator enabled in slow mode (one channel)
	I_{A5ALMH}		-	-	5	µA	Alarm comparator disabled
ALARM pin input current	I_{ALIN}	ALARM0, ALARM1	-1	-	+1	µA	T_A = 25 °C
			-3	-	+3	µA	T_A = 125 °C
ALARM pin input voltage range	V_{ALIN}		0	-	AV_{CC}	V	
External low threshold high->low transition	$V_{EVTL(H->L)}$		0.36 * AV_{CC} -0.25	0.36 * AV_{CC} -0.1	-	V	INTREF = 0
External low threshold low->high transition	$V_{EVTL(L->H)}$		-	0.36 * AV_{CC} +0.1	0.36 * AV_{CC} +0.25	V	
External high threshold high->low transition	$V_{EVTH(H->L)}$		0.78 * AV_{CC} -0.25	0.78 * AV_{CC} -0.1	-	V	
External high threshold low->high transition	$V_{EVTH(L->H)}$			0.78 * AV_{CC} +0.1	0.78 * AV_{CC} +0.25	V	
Internal low threshold high->low transition	$V_{IVTL(H->L)}$		0.9	1.1	-	V	INTREF = 1
Internal low threshold low->high transition	$V_{IVTL(L->H)}$		-	1.3	1.55	V	
Internal high threshold high->low transition	$V_{IVTH(H->L)}$		2.2	2.4	-	V	
Internal high threshold low->high transition	$V_{IVTH(L->H)}$		-	2.6	2.85	V	
Switching hysteresis	V_{HYS}		50	-	300	mV	
Comparison time	t_{COMPF}		-	0.1	1	µs	CMD = 1 (fast)
	t_{COMPS}		-	1	10	µs	CMD = 0 (slow)
Power-up stabilization time after enabling alarm comparator	t_{PD}		-	1	5	ms	Threshold levels specified above are not guaranteed within this time
Slow/Fast mode transition time	t_{CMD}		-	100	500	µs	

18.1 MCU with CAN Controller

Part number	Flash/ROM	Subclock	Persistent Low Voltage Reset	Package
MB96F347YSB PQC-GSE2	Flash A (416KB)	No	Yes	100 pin Plastic QFP (FPT-100P-M22)
MB96F347RSB PQC-GSE2			No	
MB96F347YWB PQC-GSE2		Yes	Yes	
MB96F347RWB PQC-GSE2			No	
MB96F347YSB PMC-GSE2		No	Yes	100 pin Plastic LQFP (FPT-100P-M20)
MB96F347RSB PMC-GSE2			No	
MB96F347YWB PMC-GSE2		Yes	Yes	
MB96F347RWB PMC-GSE2			No	
MB96F348YSB PQC-GSE2	Flash A (544KB)	No	Yes	100 pin Plastic QFP (FPT-100P-M22)
MB96F348RSB PQC-GSE2			No	
MB96F348YWB PQC-GSE2		Yes	Yes	
MB96F348RWB PQC-GSE2			No	
MB96F348YSB PMC-GSE2		No	Yes	100 pin Plastic LQFP (FPT-100P-M20)
MB96F348RSB PMC-GSE2			No	
MB96F348YWB PMC-GSE2		Yes	Yes	
MB96F348RWB PMC-GSE2			No	
MB96F348TSC PQC-GSE2	Flash A (544KB) Flash B (32KB)	No	Yes	100 pin Plastic QFP (FPT-100P-M22)
MB96F348HSC PQC-GSE2			No	
MB96F348TWC PQC-GSE2		Yes	Yes	
MB96F348HWC PQC-GSE2			No	
MB96F348TSC PMC-GSE2		No	Yes	100 pin Plastic LQFP (FPT-100P-M20)
MB96F348HSC PMC-GSE2			No	
MB96F348TWC PMC-GSE2		Yes	Yes	
MB96F348HWC PMC-GSE2			No	
MB96V300BRB-ES(for evaluation)	Emulated by ext. RAM	Yes	No	416 pin Plastic BGA (BGA-416P-M02)

19. Revision History

Revision	Date	Modification
Prelim 1	2007-05-07	Creation
Prelim 2	2007-05-10	External bus hold timing update
Prelim 3	2007-05-23	Electrical characteristics updates
Prelim 4	2007-08-02	Electrical characteristics updates, Product lineup, changes and ordering information
Prelim 5	2007-09-12	Addition of the electrical characteristic examples and the LVD characteristics specifications, updates of the DC characteristics. Pin circuit type drawing modifications.
Prelim 6	2007-11-21	LVD typo correction. Update of the DC characteristics. Typos corrections.
Prelim 7	2007-12-04	Absolute maximum rating asterisks numbering corrected. Typos page 59: Hardware -> Hardware. IO map table regenerated. Typos corrections. IO circuit drawings modified. Renaming of the Main/Satellite Flash into Flash memory A/B. Memory map reworked.
Prelim 8	2008-02-04	■ Satellite Flash -> 32kB Data Flash ■ MB96345 added (under development) ■ MB96F348 TSA/HSA/TWA/HWA removed (outdated devices) ■ Block diagram and pin assignment corrected (existing resource pins) ■ Pin function table corrected ■ I/O circuit type diagrams corrected ■ Memory map cleaned up ■ "Flash sector configuration" replaced by corrected "User ROM Memory map for Flash devices", “ROM configuration” replaced by “User ROM Memory map for Mask ROM devices” ■ Parallel Flash programming pinning removed ■ IO map table regenerated: ❒ Port register: Naming style corrected ❒ Memory control registers renamed (Main/Sat -> A/B) ❒ addresses after 000BFFh removed ■ Absolute maximum ratings: Pd and Ta specified more precisely ■ oscillator input levels in oscillation mode with external clock added ■ Run and Sleep mode currents: 96/48MHz and 72/36MHz settings added ■ Run mode current spec in 48/24MHz mode corrected ■ Maximum CLKS1/2 frequency for all devices correctly specified ■ Maximum CLKP2 for MB96F34xY/R/Axx corrected ■ External bus timings: missing conditions added and readability improved ■ Alarm comparator spec updated (transition voltages defined) ■ MB96V300A removed ■ Ordering information updated ■ Typos and formatting corrected